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Inclosure Material:

Metal all transistor

Overall Length:

0.188 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Diameter:

0.220 inches all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18 all transistor

Internal Junction Configuration:

Pnp all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Terminal Circle Diameter:

0.100 inches all transistor

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-15.0 collector to base voltage, dc all transistor and -15.0 emitter to base voltage, dc all transistor and -15.0 collector to emitter saturation voltage all transistor

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

150.0 milliwatts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

140.0 degrees celsius junction all transistor

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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